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OMB No. 0851-0027 (exp. 6/30/2005)

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	Please record the attached original documents or copy thereof.			
1. Name of conveying party(ies): Sung-Shan Tai and Yongzhong Hu	2. Name and address of receiving party(ies) Name: Alpha & Omega Semiconductor, LTD.			
Additional name(s) of conveying party(es) attached? La Yes La No	Internal Address:			
Assignment	Street Address: Cannon's Court 22, Victoria Street			
Execution Date: <u>Jan. 29</u> , 2007	City: Hamilton HM12, Bermuda Zip: Zip: Additional name(s) & address(es) attached? Yes No			
A. Patent Application No.(s)	cation, the execution date of the application is: $\frac{\sqrt{3a^2/7}}{2007}$ B. Patent No.(s)			
5. Name and address of party to whom correspondence concerning document should be mailed: Name: Bo-In Lin Internal Address:	6. Total number of applications and patents involved: 7. Total fee (37 CFR 3.41)\$ 40.00 Enclosed, included in PTO-2038 for enclosed Authorized to be charged to deposit account			
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ASSIGNMENT

INVENTO	R
AND CITY	/

Whereas, I, Sung-Shan Tai of 1256 Lockhaven Way,

San Jose, California 95129

have invented:

TITLE:

SPLIT GATE WITH DIFFERENT GATE MATERIALS AND WORK FUNCTIONS TO REDUCE GATE RESISTANCE OF ULTRA HIGH DENSITY MOSFET

DATE INVENTOR SIGNED THE DECLARATION and executed a United States patent application therefor

on <u>Jan. 29</u> 2007;

Whereas, Alpha & Omega Semiconductor, LTD, a Bermuda Company, having its registered address at Cannon's Court 22, Victoria Street, Hamilton HM12, Bermuda, (hereinafter called AOS), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to AOS, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to AOS its successors and assigns; and I hereby agree that AOS may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND

Signed and Sealed at Sunnyvale, California

DATE

on Jan > p 2007.

SIGNATURE OF INVENTOR

PATENT

REEL: 019045 FRAME: 0185

ASSIGNMENT

INVENTOR AND CITY

Whereas, I, YongZhong Hu of 7584 Peach Blossom Drive

Cupertino, CA 95014

have invented:

TITLE:

SPLIT GATE WITH DIFFERENT GATE MATERIALS AND WORK FUNCTIONS TO REDUCE GATE RESISTANCE OF ULTRA HIGH **DENSITY MOSFET**

DATE INVENTOR SIGNED THE **DECLARATION**

and executed a United States patent application therefor

on <u>January</u> 29, 2007;

Whereas, Alpha & Omega Semiconductor, LTD, a Bermuda Company, having its registered address at Cannon's Court 22, Victoria Street, Hamilton HM12, Bermuda, (hereinafter called AOS), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefor:

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to AOS, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to AOS its successors and assigns; and I hereby agree that AOS may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

CITY AND

Signed and Sealed at Sunnyvale, California

DATE

on January 29 2007.

SIGNATURE OF INVENTOR

PATENT REEL: 019045 FRAME: 0186

RECORDED: 01/30/2007